

TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74VHC540F, TC74VHC540FW, TC74VHC540FT
TC74VHC541F, TC74VHC541FW, TC74VHC541FT

OCTAL BUS BUFFER
TC74VHC540 F / FW / FT INVERTED, 3 - STATE OUTPUTS
TC74VHC541 F / FW / FT NON - INVERTED, 3 - STATE OUTPUTS

(Note) The JEDEC SOP (FW) is not available in Japan.

The TC74VHC540/TC74VHC541 are advanced high speed CMOS OCTAL BUS BUFFERS fabricated with silicon gate C²MOS technology.

They achieve the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

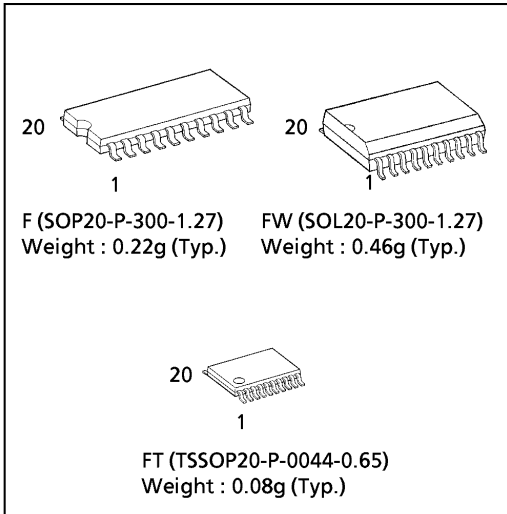
The TC74VHC540 is an inverting type, and the TC74VHC541 is a non-inverting type.

When either $\bar{G}1$ or $\bar{G}2$ are high, the terminal outputs are in the high-impedance state.

An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES :

- High Speed..... $t_{pd} = 3.7ns$ (typ.) at $V_{CC} = 5V$
- Low Power Dissipation..... $I_{CC} = 4\mu A$ (Max.) at $T_a = 25^\circ C$
- High Noise Immunity..... $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Power Down Protection is provided on all inputs.
- Balanced Propagation Delays..... $t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range..... $V_{CC} (opr) = 2V \sim 5.5V$
- Low Noise..... $V_{OLP} = 1.2V$ (Max.)
- Pin and Function Compatible with 74ALS540/541

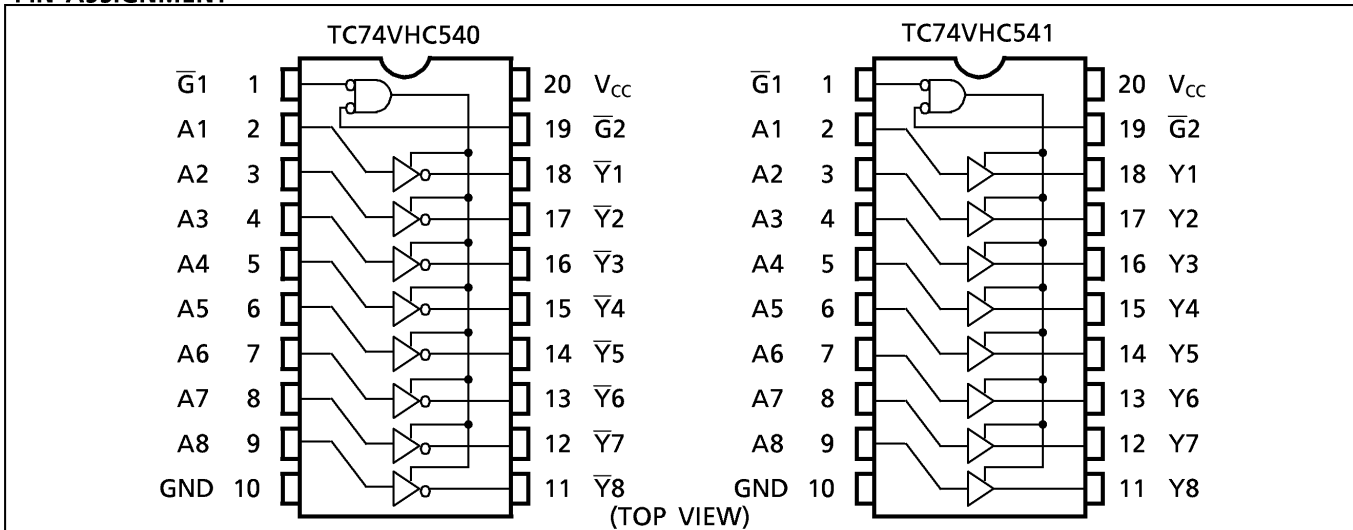


TRUTH TABLE

INPUTS			OUTPUTS	
$\bar{G}1$	$\bar{G}2$	An	Yn	$\bar{Y}n$
H	X	X	Z	Z
X	H	X	Z	Z
L	L	H	H	L
L	L	L	L	H

X : Don't Care
 Z : High Impedance
 Y_n : TC74VHC541
 \bar{Y}_n : TC74VHC540

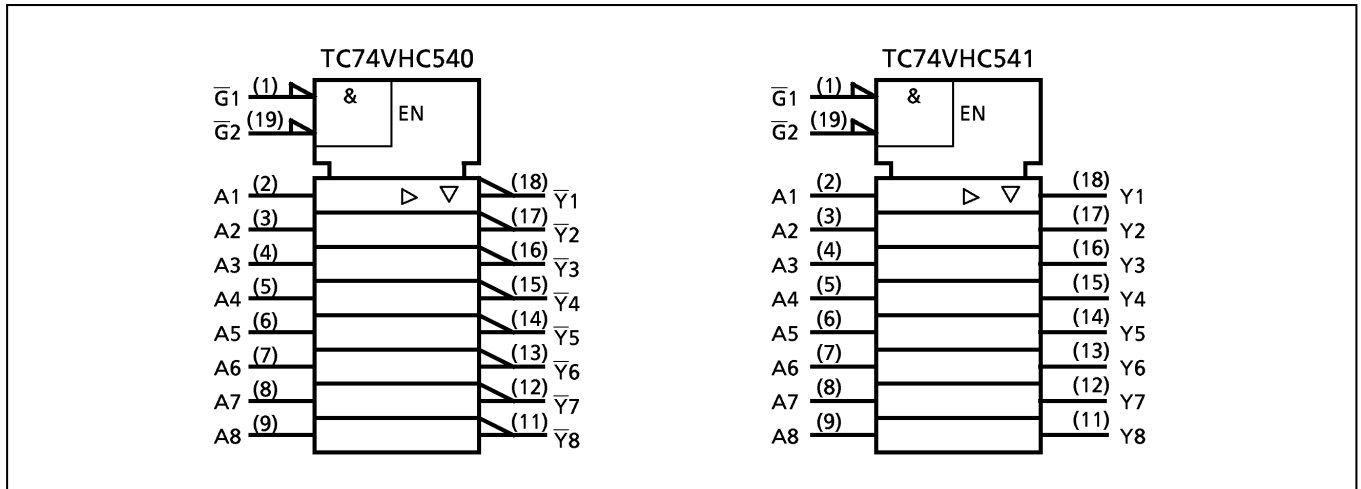
PIN ASSIGNMENT



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IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	-0.5~7.0	V
DC Input Voltage	V_{IN}	-0.5~7.0	V
DC Output Voltage	V_{OUT}	-0.5~ $V_{CC} + 0.5$	V
Input Diode Current	I_{IK}	-20	mA
Output Diode Current	I_{OK}	±20	mA
DC Output Current	I_{OUT}	±25	mA
DC V_{CC} /Ground Current	I_{CC}	±75	mA
Power Dissipation	P_D	180	mW
Storage Temperature	T_{stg}	-65~150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V_{CC}	2.0~5.5	V
Input Voltage	V_{IN}	0~5.5	V
Output Voltage	V_{OUT}	0~ V_{CC}	V
Operating Temperature	T_{opr}	-40~85	°C
Input Rise and Fall Time	dt / dv	0~100 ($V_{CC} = 3.3 \pm 0.3V$) 0~20 ($V_{CC} = 5 \pm 0.5V$)	ns / V

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DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	Ta = 25°C			Ta = -40~85°C		UNIT	
				MIN.	TYP.	MAX.	MIN.	MAX.		
High - Level Input Voltage	V _{IH}		2.0 3.0~ 5.5	1.50 V _{CC} × 0.7	— —	— —	1.50 V _{CC} × 0.7	—	V	
Low - Level Input Voltage	V _{IL}		2.0 3.0~ 5.5	— —	— —	0.50 V _{CC} × 0.3	— —	0.50 V _{CC} × 0.3	V	
High - Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50μA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
			I _{OH} = -4mA I _{OH} = -8mA	4.5	4.4	4.5	—	4.4	—	
				3.0	2.58	—	—	2.48	—	
				4.5	3.94	—	—	3.80	—	
Low - Level Output Voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50μA	2.0	—	0.0	0.1	—	0.1	V
				3.0	—	0.0	0.1	—	0.1	
			I _{OL} = 4mA I _{OL} = 8mA	4.5	—	0.0	0.1	—	0.1	
				3.0	—	—	0.36	—	0.44	
				4.5	—	—	0.36	—	0.44	
3 - State Output Off - State Current	I _{OZ}	V _{IN} = V _{IH} or V _{IL} V _{OUT} = V _{CC} or GND	5.5	—	—	±0.25	—	±2.50	μA	
Input Leakage Current	I _{IN}	V _{IN} = 5.5V or GND	0~5.5	—	—	±0.1	—	±1.0		
Quiescent Supply Current	I _{CC}	V _{IN} = V _{CC} or GND	5.5	—	—	4.0	—	40.0		

AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3\text{ns}$)

PARAMETER	SYMBOL	TEST CONDITION		Ta = 25°C			Ta = -40~85°C		UNIT
		V _{CC} (V)	CL (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	
Propagation Delay Time (TC74VHC540)	t _{pLH}	3.3 ± 0.3	15	—	4.8	7.0	1.0	8.5	ns
			50	—	7.3	10.5	1.0	12.0	
	t _{pHL}	5.0 ± 0.5	15	—	3.7	5.0	1.0	6.0	
			50	—	5.2	7.0	1.0	8.0	
Propagation Delay Time (TC74VHC541)	t _{pLH}	3.3 ± 0.3	15	—	5.0	7.0	1.0	8.5	
			50	—	7.5	10.5	1.0	12.0	
	t _{pHL}	5.0 ± 0.5	15	—	3.5	5.0	1.0	6.0	
			50	—	5.0	7.0	1.0	8.0	
3-State Output Enable Time	t _{pZL}	RL = 1kΩ	3.3 ± 0.3	15	—	6.8	10.5	1.0	12.5
				50	—	9.3	14.0	1.0	16.0
	t _{pZH}		5.0 ± 0.5	15	—	4.7	7.2	1.0	8.5
				50	—	6.2	9.2	1.0	10.5
3-State Output Disable Time	t _{pLZ}	RL = 1kΩ	3.3 ± 0.3	50	—	11.2	15.4	1.0	17.5
				50	—	6.0	8.8	1.0	10.0
t _{pHZ}	5.0 ± 0.5		50	—	6.0	8.8	1.0	10.0	
			50	—	6.0	8.8	1.0	10.0	
Output to Output Skew	t _{osHL}	(Note 1)	3.3 ± 0.3	50	—	—	1.5	—	1.5
				50	—	—	1.0	—	1.0
t _{osLH}	5.0 ± 0.5		50	—	—	1.0	—	1.0	
			50	—	—	1.0	—	1.0	
Input Capacitance	C _{IN}			—	4	10	—	10	pF
Output Capacitance	C _{OUT}			—	6	—	—	—	
Power Dissipation Capacitance (Note 2)	C _{PD}	TC74VHC540		—	17	—	—	—	
		TC74VHC541		—	18	—	—	—	

Note (1) Parameter guaranteed by design. $t_{osLH} = |t_{pLHm} - t_{pLHn}|$, $t_{osHL} = |t_{pHLm} - t_{pHLn}|$

Note (2) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

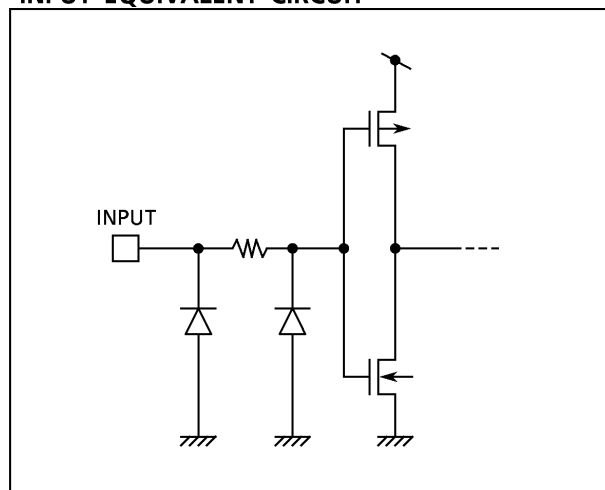
$$I_{CC(opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 8 \text{ (per bit)}$$

NOISE CHARACTERISTICS (Input $t_r = t_f = 3ns$)

PARAMETER	SYMBOL	TEST CONDITION	Ta = 25°C			UNIT
			V _{CC} (V)	TYP.	LIMIT	
Quiet Output Maximum Dynamic VOL	VOLP	CL = 50pF	5.0	0.7 (0.9)	1.0 (1.2)	V
Quiet Output Minimum Dynamic VOL	VOLV	CL = 50pF	5.0	-0.7 (-0.9)	-1.0 (-1.2)	V
Minimum High Level Dynamic Input Voltage	VIHD	CL = 50pF	5.0	—	3.5	V
Maximum Low Level Dynamic Input Voltage	VILD	CL = 50pF	5.0	—	1.5	V

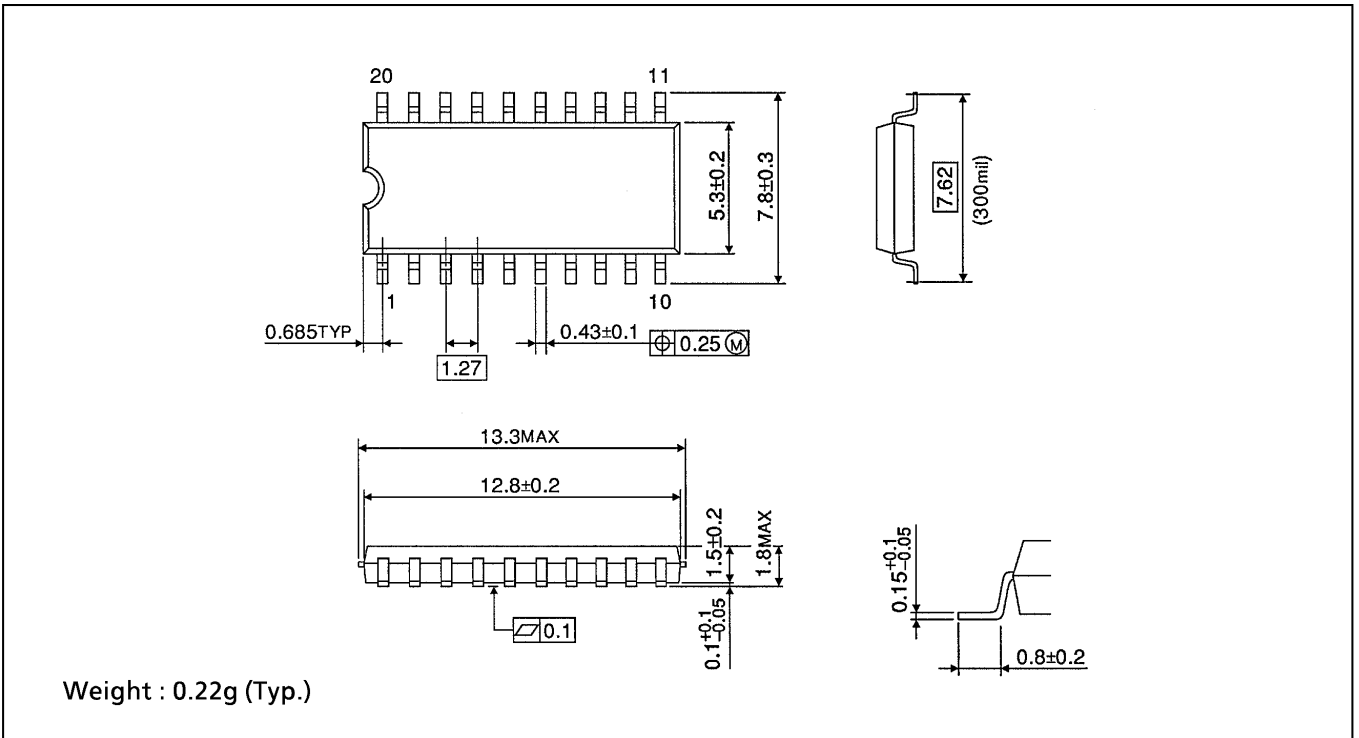
(Note) The value in () only applies to JEDEC SOP (FW) devices.

INPUT EQUIVALENT CIRCUIT



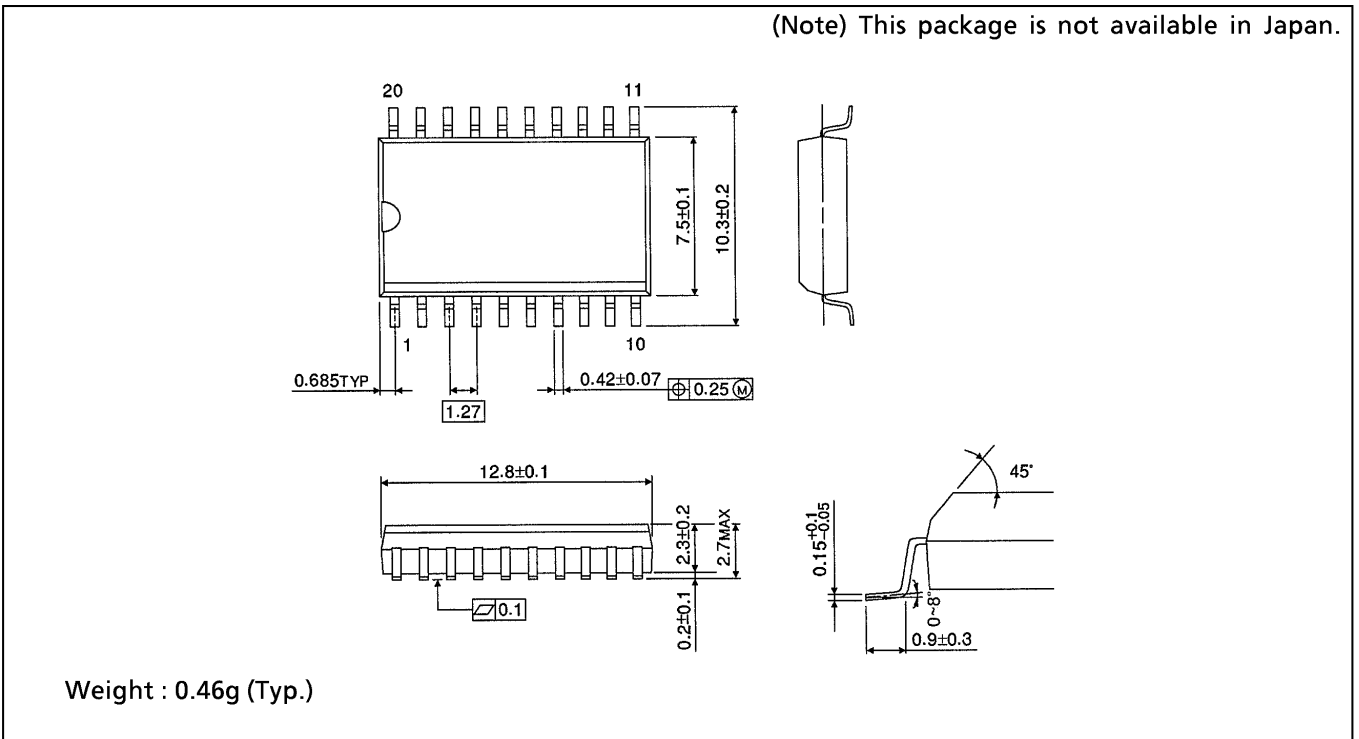
SOP 20PIN (200mil BODY) OUTLINE DRAWING (SOP20-P-300-1.27)

Unit in mm



SOP 20PIN (300mil BODY) OUTLINE DRAWING (SOP20-P-300-1.27)

Unit in mm



TSSOP 20PIN OUTLINE DRAWING (TSSOP20-P-0044-0.65)

Unit in mm

